UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/673,467	09/30/2003	Eric J. Strang	231752US6YA	2006
	7590 11/19/200 AK, MCCLELLAND 1	EXAM	EXAMINER	
1940 DUKE ST ALEXANDRIA	TREET	SAXENA, AKASH		
ALEAANDIGA	A, VA 22514		ART UNIT	PAPER NUMBER
		2128		
		,		
			NOTIFICATION DATE	DELIVERY MODE
•			11/19/2007	ELECTRONIC

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

patentdocket@oblon.com oblonpat@oblon.com jgardner@oblon.com

	Application No.	Applicant(s)
	10/673,467	STRANG, ERIC J.
Office Action Summary	Examiner	Art Unit
	Akash Saxena	2128
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).
Status		
1) Responsive to communication(s) filed on 06 Ap	oril 2007.	
2a) This action is FINAL . 2b) ⊠ This	action is non-final.	
3) Since this application is in condition for allowar closed in accordance with the practice under E		•
Disposition of Claims	•	
4)⊠ Claim(s) <u>1-61</u> is/are pending in the application.		
4a) Of the above claim(s) is/are withdraw	vn from consideration.	
5) Claim(s) is/are allowed.		•
6)⊠ Claim(s) <u>1-61</u> is/are rejected.		
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction and/or	r election requirement.	
Application Papers		
9) The specification is objected to by the Examine	r.	
10) The drawing(s) filed on is/are: a) acce	epted or b) \square objected to by the I	Examiner.
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correct	· · · · · · · · · · · · · · · · · · ·	•
11) ☐ The oath or declaration is objected to by the Ex	caminer. Note the attached Office	Action or form PTO-152.
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign	priority under 35 U.S.C. § 119(a))-(d) or (f).
a) ☐ All b) ☐ Some * c) ☐ None of:		
 Certified copies of the priority documents 	s have been received.	
2. Certified copies of the priority document	• •	
3. Copies of the certified copies of the prior	•	ed in this National Stage
application from the International Bureau		
* See the attached detailed Office action for a list	or the certified copies not receive	9 0.
	•	
Attachment(s)	4) Interview Summary	(PTO-413)
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail D	ate
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 11/5/07.	5) Notice of Informal F 6) Other:	Patent Application

Application/Control Number: 10/673,467 Page 2

Art Unit: 2128

DETAILED ACTION

 Claim(s) 1-61 has/have been presented for examination based on amendment filed on 6th July 2007.

- 2. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 6th July 2007 has been entered.
- 3. Claim(s) 58 is/are amended.
- 4. Claim(s) 58 remain rejected under 35 USC § 101.
- 5. Claim(s) 1-61 remain rejected under 35 USC § 112.
- 6. Claim(s) 1-61 remain rejected under 35 USC § 103.
- 7. The arguments submitted by the applicant have been fully considered. Claims 1-61 remain rejected and this action is made NON-FINAL. The examiner's response is as follows.

Claim Rejections - 35 USC § 101 and response the applicant's remarks

8. Examiner maintains the claim rejection(s) under 35 USC § 101 to claim(s) 58 in view of the applicant's amendment and disclosure on page 33 of the specification. Please see updated rejection below.

Claim Rejections - 35 USC § 101

35 U.S.C. 101 reads as follows:

Whoever invents or discovers any new and useful process, machine, manufacture, or composition of matter, or any new and useful improvement thereof, may obtain a patent therefor, subject to the conditions and requirements of this title.

9. Claim 58 is rejected under 35 U.S.C. 101 because the claimed invention is directed to non-statutory subject matter. Specifically, the claim recites "a computer readable medium encoded with computer program" which in the defined in the specification Pg.33 [00103] as:

A computer readable medium may take many forms, including but not limited to, non-volatile media, volatile media, and <u>transmission media</u>.... Transmission media also may also take the form of <u>acoustic or light waves</u>, <u>such as those generated during radio wave and infrared data communications</u>.

The claims remains non-statutory it is directed towards volatile media and forms of energy (transmission media, carrier wave). The rejection is maintained.

Response to Double Patenting

10. Applicant's arguments relating to filing a terminal disclaimer for applications 10/673,507, 10/673,501, 10/673,138, 10/673,583 (Added) are considered and double patenting rejection is maintained until a terminal disclaimer is filed.

Art Unit: 2128

Response to Applicant's Remarks for 35 U.S.C. § 103

11. Claims 1-21, 23, 25-48, 50 and 52-58 were rejected under 35 U.S.C. 103(a) as being unpatentable over Sonderman, in view of Chen, further in view of Jain.

Regarding Claims 1-21, 23, 25-48, 50 and 52-58

(Argument 1) Applicant has argued the following:

Applicant respectfully disagrees with the examiner's asserted position that it is physically not possible to have the first principle simulations of the actual process be performed at the same time with the actual process and then use the result to perform the actual process on the same wafer. Any process in a semiconductor-processing tool takes a specific amount of time to run. During this run time, the present invention can take data from the actual ongoing process and use a first principles simulation to provide a first principles simulation result in accordance with the process data, as specifically claimed. [1] The result could be for example a trajectory of how the process will evolve with time. The result may further as claimed be used to generate or supplement an empirical model for the reactor.

Applicant discloses in numbered paragraph [0067] of the filed specification that [2]:

Specification [0067]

[0067] However, for these statistical methods to be able to reliably sense and control the tool under widely varying operating conditions, the database must be broad-enough to cover all operating conditions, which makes the database a burden to produce. The on-tool first principles simulation capability of the present invention does not require the creation of any such database because tool response to process conditions is predicted from physical first principles directly and accurately, given accurate working models and accurate input data. However, statistical methods can still be used to refine working models and input data as more run-time information under different operating conditions becomes available, but having such information is not required by the present invention for process sensing and control capability. Indeed, the process model Can provide a basis upon which the process can be empirically controlled by using the process model to extend those known empirical solutions to "solutions" where empirical results have not been physically made. Hence, the present invention in one embodiment empirically characterizes the process tool by supplementing the known (i.e. physically observed) Solutions with first principle simulation module solutions, the simulation module solutions being consistent with the known solutions. Eventually, as better statistics develop, the simulation module solutions can be superseded by the database of empirical solutions.

Moreover, because of the Applicant's use of features as defined for example in Claims 15-21 and Claim 59, the time to perform the first principle's simulation is now commensurate with the time of a semiconductor process run and permits the present invention to overcome what the examiner see as an impossibility. That is, "it is physically not possible to have the first principle simulation of the actual process to be performed at same time with actual process and then use the result to perform the actual process on the same wafer." This assessment by the examiner based on the examiner's understanding of Sonderman et al, under KSR International Co. v. Teleflex Inc. et al. 2007 U.S. LEXIS 4745 (to be discussed later), should be prima facie evidence of the non-obviousness of the claims.

(Response 1) Examiner thanks applicant for providing clarification [1], however the cited section of the specification teaches of first principle simulation model with and without database [2] and does not teach the argument made in [1] that Any process in a semiconductor-processing tool takes a specific amount of time to run. During this run time, the present invention can take data from the actual ongoing process and use a first principles simulation to provide a first principles simulation result in accordance with the process data, as specifically claimed.

Arguendo if examiner's position is incorrect, applicant asserted advantages [1] are not sufficient to overcome the rejection(s) of record because it is not supported by the specification.

Secondly, in view of arguments made with KSR, Lack of critical/essential elements constituting an enabling disclosure cannot be obviated with common knowledge, where the implied speed of simulation is not supported by critical details (<u>essential matter</u>) of the First Simulation Model that makes the First Simulation Model faster. In this case the claim omits the details and cannot be obvious. MPEP 2172.01 states:

A claim which omits matter disclosed to be essential to the invention as described in the specification or in other statements of record may be rejected under 35 U.S.C. 112, first paragraph, as not enabling. In re Mayhew, 527 F.2d 1229, 188 USPQ 356 (CCPA 1976). See also MPEP § 2164.08(c). Such essential matter may include missing elements, steps or necessary structural cooperative relationships of elements described by the applicant(s) as necessary to practice the invention.

(Argument 2) Applicant has cited Sonderman Col.9 Lines 46-51

The system 100 then optimizes the simulation (described above) to find more optimal process target (T.sub.i) for each silicon wafer, S.sub.i. to be processed. These target values are then used to generate new control inputs, X.sub.Ti, on the line 805 to control a subsequent process of a silicon wafer S.sub.i [Emphasis added by examiner]. The new control inputs, X.sub.Ti, are generally based upon a plurality of factors, such as simulation data, output requirements, product performance requirements, process recipe settings based on a plurality of processing tool 120 operating scenarios, and the like.

with the following argument:

Thus, this section of Sonderman et al clearly discloses that the simulation is to find a more optimum process target for each silicon wafer to be processed. The simulation results produce a new control input for the silicon wafer to be processed. Thus, Applicant respectfully submits that Sonderman et al. teach performing first principles simulation for the actual process to be performed before performance of the actual process, and not the claimed performing first principles simulation for the actual process being performed during performance of the actual process.

(Response 2) Applicant emphasized section of Sonderman is bolded and italicized.

Examiner cited portion is bolded and underlined.

Examiner disagrees with the applicant that argument because the results of the simulation are applied to the same semiconductor. Sonderman clearly states each silicon wafer S.sub.i is exposed to new control inputs for subsequent processing (not subsequent wafer in the next round as indicated by second underlined phrase). If the intent of Sonderman <u>not</u> was to indicate that new control inputs generated by simulation for the actual process being performed during performance of the actual process, he would have stated it is applied to the subsequent <u>silicon wafer S.sub.i+1</u>. Instead the inputs are applied to the same silicon wafer <u>S.sub.i</u>. Applicant's arguments are unpersuasive.

(Argument 3) Applicant has cited Fig.4 from Sonderman requiting the steps in Fig.4 and presenting the following argument.

Art Unit: 2128

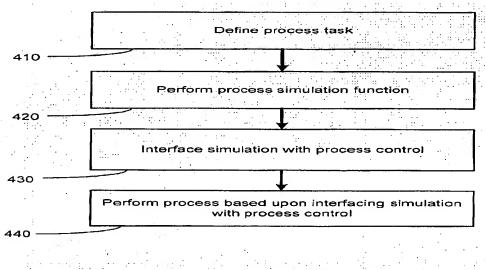


FIGURE 4

Hence, the process flow in Sonderman et al is straightforward:

- 1) define process to be modeled,
- 2) model process for simulation result,
- 3) interface simulation result to processor, and then
- 4) run the process under control based on the pre-existing simulation result.

Note also that this sequence in Sonderman et al means that Sonderman et al do not disclose inputting process data relating to an actual process being performed by the semiconductor processing tool, as also claimed. Rather, Sonderman et al use data from previous runs to produce a simulation result.

Accordingly, Applicant respectfully submits that Sonderman et al do not disclose and indeed teach away from the present invention.

(Response 3) Examiner thanks applicant for their interpretation, however the interpretation is incomplete with the reference that this process involves a feedback, therefore the applicant's assertion that control is based on the pre-existing simulation result and Sonderman et al does not disclose inputting process data relating to an actual process being performed by the semiconductor processing tool is incorrect. Sonderman Col.4 Line 65-Col.5 Line 10 states:

Furthermore, the simulation environment 210 can be used for feedback modification of control parameters invoked by the process control environment 180. For example, the manufacturing environment 170 can send metrology data results into the simulation environment 210. The simulation environment 210 can then use the metrology data results and perform various tests and calculations to provide more accurate, modified control parameters to the process control environment 180. A feedback loop in then completed when the process control environment 180

Art Unit: 2128

sends the modified or adjusted process control parameters to the manufacturing environment 170 for further processing of semiconductor wafers.

Sonderman clearly teaches inputting process data relating to an actual process being performed by the semiconductor processing tool, into the simulator and applying the simulation result to the semiconductor-processing tool.

Further in support of examiner's argument, applicant is also performing the same process of feedback modification (See specification Fig.7). In conclusion, Sonderman does not teach away from the claimed invention and applicant's arguments are found to be unpersuasive.

(Argument 4) Applicant has argued that Jain does not overcome the deficiencies of Sonderman.

(Response 4) Applicant's arguments fail to comply with 37 CFR 1.111(b) because they amount to a general allegation that the claims define a patentable invention without specifically pointing out how the language of the claims patentably distinguishes them from the references. Applicant has merely cited portion of Jain without clearly showing why Jain does not overcome the deficiencies of Sonderman.

(Argument 5) Applicant has stated the following:

Moreover, the proposed development work in Jain is understood better in the light of the "conventional approach" referred to by Kee et al, made of record by the Information Disclosure Statement filed December 20, 2005.

Further arguments are presented with current case law KSR International Vs. Teleflex Inc.

(Response 5) First, Kee et al is not used as prior art for rejecting the current invention. Secondly, examiner fails to see the connection between Jain and Kee et

al as neither of them reference to each other in any way. Thirdly, Applicant also has not further established why the so-called "conventional approach" would link them. In light of the above applicant's arguments are found to be unpersuasive. Fourthly, the limitations of being First Principle Simulation being faster than actual process is not claimed; and even if claimed does not present a limitation as what makes First Principle Simulation faster is not disclosed.

(Argument 6) Applicant has argued:

In the present situation, the claimed method of performing a first principles simulation for the actual process being performed during performance of the actual process <u>produces more than an expected result in that Sonderman et al</u> (*in having to develop a new control inputs for each subsequent wafer*) can not compensate for real time excursions from the existing model occurring while the wafer is being processed. In other words, the <u>lengthy time for generation of a first principles model simulation</u> in the prior art prevents one from realizing a real time process control based on a first principles simulation during the actual process. <u>Indeed, as pointed out above, the examiner considered it an impossibility to simultaneously perform a first principles simulation result and to control the actual process being run with the first principles simulation result [3]. Hence, the claimed processes and systems produce an unexpected result [4].</u>

(Response 6) Examiner thanks applicant for the remarks above, however the new control inputs are not developed for the processing of each subsequent wafer, but instead are for subsequent processing [performed on] a silicon wafer S.sub.i (Sonderman: Col.9 Lines 44-46 – this point is also addressed above in response to argument 1).

Further <u>most importantly</u> applicant is arguing limitation, which are <u>not</u> present in the claim and <u>may</u> constitute patentable subject matter. Specifically, as indicated by applicant "the <u>lengthy time for generation of a first principles model simulation</u> in the prior art prevents one from realizing a real time process control based on a first principles simulation during the actual process." However, this is the conclusory statement, where <u>what makes</u> the

Page 10

Application/Control Number: 10/673,467

Art Unit: 2128

current first principle simulation model realize the real time process control possible is not claimed. Further distinguishing it from Sonderman may also help in defining a more patentable subject matter. Also see MPEP 2172.01 cited above.

Applicant has quoted examiner [3] bolstering their position of unexpected result [4], however it is only unexpected because it is not enabled in the specification – specifically what makes the First Principle Simulation faster than models disclosed in prior art is not present in the specification.

Further, applicants in arguing that "Indeed, as pointed out above, the examiner considered it an impossibility to simultaneously perform a first principles simulation result and to control the actual process being run with the first principles simulation result", render the above premise of unexpected result [4] false by their own admission. Applicant's argument would have merit if Applicants agreed that it was impossible. In any case, Applicants speculate but provide no evidence in the specification (See Drawings Fig.8).

Viewed differently, applicant's position on this matter is consistent with a number of the Graham factors identified in MPEP 2141 III as objective evidence of non-obviousness.

End of Respons	to 35 USC 103 Arguments	
----------------	-------------------------	--

Art Unit: 2128

Claim Rejections - 35 USC § 112¶1st and response the applicant's remarks

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

12. Claim 1-51 are rejected under 35 U.S.C. 112, first paragraph, as based on a disclosure which is not enabling. Exact details of what basic physical and chemical attribute of the semiconductor processing tool are used to construct a first principle simulation model which is critical or essential to the practice of the invention, but not included in the claim(s) is not enabled by the disclosure. See *In re Mayhew*, 527 F.2d 1229, 188 USPQ 356 (CCPA 1976).

Applicant has argued citing specification paragraphs [0035] and [0036] as to what constitutes first principle physical model.

(Response to applicant's remarks)

Applicant has provided an exact support in disclosure for such attributes in the model. Applicant has incorrectly quoted specification paragraphs [0035] and [0036]. These paragraph are not enabling although they rely on the commercially available packages to model the various first principle simulation models, the details of the model are absent from the specification. The details of these model which lead to unexpected results (Argument & response 5) are very relevant to the designing the first principle physical model. Examiner respectfully maintains the rejection. Further please see MPEP 2172.01 cited above.

Art Unit: 2128

Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

13. Claim 1, 26, 55 and 56 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claim 1, 38, 75 and 78 of copending Application No. 10/673,507 (updated 9/19/06) respectively.

Application No. 10/673,467	Application No. 10/673,507
A method of controlling a process performed by a semiconductor processing tool, comprising:	A method of controlling a process performed by a semiconductor processing tool, comprising:
inputting data relating to a process performed by the semiconductor processing tool;	inputting data relating to a process performed by the semiconductor processing tool;
inputting a first principles physical model including a set of computer-encoded differential equations, the first principles physical model describing at least one of a basic physical or chemical attributes of the semiconductor processing tool;	inputting a first principles physical model including a set of computer-encoded differential equations, the first principles physical model describing at least one of a basic physical or chemical attribute of the semiconductor processing tool;
performing first principles simulation for the actual process being performed using the input data and the physical model to provide a first principles simulation result in accordance with the process data relating to the actual process being performed in order to simulate the actual process being	performing first principles simulation for the actual process being performed using the physical model to provide a first principles simulation result in accordance with the process data relating to the actual process being performed in order to simulate the actual process being performed; and

Page 13

Application/Control Number: 10/673,467

Art Unit: 2128

performed;	·
using the first principles simulation result to build an empirical model; and	
selecting at least one of the first principles simulation result and the empirical model to control the process performed by the semiconductor processing tool.	and using the first principles simulation result to control the <u>actual</u> process performed by the semiconductor processing tool.

Although the conflicting claims are not identical, they are not patentably distinct from each other because the step of building an empirical model is inherent with the physical model. Further, both the specifications are identical in implementation and there is no difference in the implementation of the two models. This is a provisional obviousness-type double patenting rejection because the conflicting claims have not in fact been patented. Further the step of "selecting" which not present in the 10/673,507, is evident in the using the result to control the actual process.

14. Further, at least Claim 1 is also provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claim 1 of copending Application No. 10/673,501, 10/673,138, 10/673,583.

The steps of controlling, inputting data, inputting a first principle physical model, performing simulation and selecting/using results are almost identical in the both the claim 1 sets for the co-pending applications. Other independent claims in the copending applications are rejectable similarly.

----- End of Double Patenting Rejection -----

Art Unit: 2128

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.
- 3. Resolving the level of ordinary skill in the pertinent art.
- Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 15. Claims 1-21, 23, 25-48, 50 and 52-61 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 6,802,045 issued to Sonderman et al (Sonderman hereafter), in view of U.S. Patent No. 5,719,796 issued to Vincent M.C. Chen (Chen hereafter), in view of IEEE article "Mathematic-physical engine: parallel processing for modeling and simulation of physical phenomena" by Jain et al (Jain hereafter).

Regarding Claim 1 (Updated)

Sonderman teaches a method to controlling a process performed by a semiconductor-processing tool (Sonderman: Summary, at least in Col.2 Lines 10-17;Col.3 Lines 45-49) by inputting *process* data relating to *an actual* process *being* performed by the semiconductor-processing tool (Sonderman: at least in Col.3 Lines

50-67; Col.7 Lines 8-20). Further, Sonderman teaches inputting the first principle physical model relating to the semiconductor-processing tool describing at least one of a basic physical or chemical attributes (Sonderman: at least in Col.5 Lines 11-17; 49-67) as device physics model, a process model and an equipment model. Further, Sonderman teaches performing first principle simulation for the actual process being performed during performance of actual process (Sonderman: Col.7 Lines 4-7; Col.3 Lines 56-63; Fig. 1-3) using the input data and the physical model to provide simulation results for the process performed by the semiconductor–processing tool (Sonderman: at least in Col.5-7). Further, Sonderman teaches using the first principle simulation results obtained during the performance of the actual process (Sonderman: Fig. 1-3 Col.7 Lines 4-7; Col.3 Lines 56-63) to control the actual process being performed by the semiconductor-processing tool (Sonderman: at least in Col.4 Lines 48-64; Fig.1-8; Col.2 Lines 10-17).

Sonderman does not explicitly teach building an empirical model and using the first principle simulation results along with the empirical model to control the process performed by the semiconductor-processing tool. Empirical model & library as understood from the specification ([0078]) is the database of the simulation results, which provides "statistically sufficient sample of the parameter space".

Chen teaches creating an empirical model as disclosed in the specification as a statistical model built based on run-to-run or batch-to-batch results and using the results to control the process performed by the semiconductor-processing tool as well as to the next simulation step (Chen: Col.3 Lines 12-47; Col.6 Lines 34-67).

Art Unit: 2128

Sonderman and Chen do not teach first principle model including a set of computer encoded differential equations.

Jain teaches computer encoded differential equations using MPE engine, which can be applied to wafer processing (Jain: Abstract). Jain also teaches dedicated and wafer level implementation of MPE engine to provide enhanced performance (Jain: Pg. 372 Section V Dedicated MPE).

It would have been obvious to one (e.g. a designer) of ordinary skill in the art at the time the invention was made to apply the teachings of <u>Chen to Sonderman</u>. The motivation to combine would have been that Chen and Sonderman both are analogous art concerned with simulating the semiconductor fabrication process and providing the best control parameters to the actual semiconductor-processing tool (Chen: at least in Col.3 Lines 19-23).

It would have been obvious to one (e.g. a designer) of ordinary skill in the art at the time the invention was made to apply the teachings of <u>Jain to Sonderman</u> to solve differential equation for the semiconductor processing tool. Sonderman teaches building various models, which work in real-time feedback control simulating actual semiconductor modeling process (Sonderman: Fig.1; *Col.7 Lines 8-20*), while Jain makes possible by providing model-solving capacity in real time when differential equations are present in the model (like thermal patterns in semiconductor wafer model) (Jain: Abstract).

Regarding Claim 2

Sonderman teaches directly inputting the *process* data relating to the *actual* process *being* performed by the semiconductor-processing tool from at least one of physical sensor (eg. Scatterometry data, overlay data, dimensional data) and a metrology tool physically mounted on the semiconductor-processing tool (Sonderman: at least in Col.4 Lines 31-48; Col.4-8; Fig.1, 7; *Col.7 Lines 8-20*).

Regarding Claims 3-5

Sonderman teaches indirectly inputting the *process* data relating to the *actual* process performed by the semiconductor-processing tool from one of the manual input devices and a database as manual fashion data retrieval and automatic data retrieval; inputting data recorded from the previous run; inputting the data set by a simulation operator (Sonderman: at least in Fig.1-3 Col.1; Col.4-7; Col.7 Lines 8-20).

Regarding Claims 6-9

Sonderman teaches inputting *process* data relating to at least one of the physical characteristics of the semiconductor-processing tool and semiconductor tool environment, data relating to at east on of the characteristics and a result of a process performed by the semiconductor processing tool; inputting a spatially resolved model (as modified models) of the geometry of the semiconductor processing tool; inputting fundamental equations necessary to perform first principle simulation for the desired simulation result (Sonderman: at least in Col.5 Lines 10-18; Col.6 Lines 48-63; Col.9 (equations); Col.5-9; Fig 1-3; *Col.7 Lines 8-20*). Sonderman and Jain teach inputting fundamental equations *as the set of computer*

Art Unit: 2128

encoded differential equations (Sonderman: Col.9 (equations); Jain: Pg. 372 Section V Dedicated MPE, Abstract).

Regarding Claim 10

Sonderman teaches performing interaction concurrently between the simulation environment (first principle simulation) and the semiconductor-processing tool (Sonderman: Fig.2; Col.4 Lines 48-63).

Regarding Claims 11-13

Sonderman teaches performing first principle simulation independent of the process performed by the semiconductor-processing tool; inputting data from to set initial & boundary condition on the first simulation model (Sonderman: at least in Col.5-8; Fig.3-4).

Regarding Claim 14

Sonderman teaches using the first principles simulation result comprises using the first principles simulation result to perform at least one of detecting, and classifying a fault in the process performed by the semiconductor-processing tool (Sonderman: at least in Col.5 Line 56 – Col.6 Line 24).

Regarding Claims 15-19 (Updated)

Sonderman teaches using a network of interconnected resources <u>inside the</u>

<u>semiconductor manufacturing facility (Sonderman: Semiconductor tools on the</u>

<u>factory floor – Col.9 Lines 60-65</u>) to perform <u>first principle simulation (Jain: Section</u>

<u>III)</u> recited in claim 1; using code parallelization among interconnected computational resources to share the computational load of the first principle simulation; sharing

Application/Control Number: 10/673,467 Page 19

Art Unit: 2128

simulation information among the interconnected resources to facilitate a process by the semiconductor-processing tool; sharing simulation results among the interconnected resources to reduce redundant execution of substantially similar first principle simulation by different resources; sharing information comprising model changes among the interconnected resources to reduce the redundant refinements of first simulation by different resources (Sonderman: Fig.1-3, computer code software is described in Col.9 Lines 58 onward; Col.5-8).

Regarding Claims 20-21 (Updated)

Sonderman teaches remote access to computational and storage resources (Sonderman: Col.9 Line 58-Col.10 Line 31) where in wide area network is art inherent. *The claim dependency is changed from claim 15 to claim 1 for claim 20.*

Sonderman teaches first principle simulation controlling at least one of a material processing system, an etch system, a photoresist spin coating system, a lithography system, a dielectric coating system, a deposition system, a rapid thermal processing system for thermal annealing, and a batch diffusion furnace (Sonderman: at least in Col 4 Lines 18-31; Col.3 Lines 45-49).

Regarding Claim 25

Regarding Claim 23

Sonderman teaches inputting various parameters relating to etching, deposition etc. (Sonderman: at least in Col.5 Lines 56-67)

Art Unit: 2128

Regarding Claim 26

Sonderman teaches inputting physical geometric data as parameters for the equipment model where the equipment could be at least one of a material processing system, an etch system, a photoresist spin coating system, a lithography system, a dielectric coating system, a deposition system, a rapid thermal processing system for thermal annealing, and a batch diffusion furnace (Sonderman: Col.5 Lines 56-67).

Regarding Claim 27

Sonderman teaches first principles simulation result controlling the semiconductor processing tool by using model output to adjust said process performed by the semiconductor processing tool (Sonderman: Col.4 Lines 48-64; Fig.1-2).

Regarding Claim 28-48 (Updated)

System claims 28-48 disclose similar limitations as claims 1-21 and are rejected for the same reasons as claims 1-21 respectively.

Regarding Claim 50, 52-54

System claims 50 & 52-54 disclose similar limitations as claims 23 & 25-27 and are rejected for the same reasons as claims 23 & 25-27 respectively.

Regarding Claim 55

System claim 55 discloses similar limitations as claim 1 and is rejected for the same reasons as claim 1.

Application/Control Number: 10/673,467 Page 21

Art Unit: 2128

Regarding Claim 56 & 57 (Updated)

System claims 56 & 57 disclose similar limitations as claims 16 & 17 and are rejected for the same reasons as claims 16 & 17 respectively.

Regarding Claim 58 (Updated)

Article of Manufacture (computer program) claim 58 discloses similar limitations as claim 1 and is rejected for the same reasons as claim 1.

Regarding Claims 59-61(New Claims)

Jain teaches use of Navier Stokes and other known simulation solutions (reuse) for solving various simulation problems as initial condition (Jain: Pg. 367-368 Section "Governing Rationale" Sub-Section A. Governing Equations). Sonderman also teaches initializing the models with input data (Sonderman: Col.7 Lines 8-20).

4. Claims 22 and 49 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 6,802,045 issued to Sonderman et al (Sonderman hereafter), in view of U.S. Patent No. 5,719,796 issued to Vincent M.C. Chen (Chen hereafter), in view of IEEE article "Mathematic-physical engine: parallel processing for modeling and simulation of physical phenomena" by Jain et al (Jain hereafter), further in view of IEEE article "Heat Analysis on Insulated Metal Substrates" by Naomi Yunemura et al (Yunemura hereafter).

Regarding Claim 22

Teachings of *Sonderman, Chen and Jain* are disclosed in claim 1 rejection above.

Sonderman also teaches that the first principle simulation models the equipment

Art Unit: 2128

conditions, thereby modeling temperature response and pressure response during various processes (Sonderman: at least in Col.5 Lines 62-67).

Sonderman, Chen and Jain does not teach explicitly that such temperature and pressure modeling is done using ANSYS computer code. However, Jain teaches SIMD based processing to solve the computer-encoded differential equations (Jain: Pg. 370 Section III Parallel architectures for solving PDE).

Yunemura teaches that heat simulation modeling can be performed using ANSYS computer code (Yunemura: Pg. 1407 Section 1) on a silicon chip.

It would have been obvious to one (e.g. a designer) of ordinary skill in the art at the time the invention was made to apply the teachings of Yunemura to Sonderman, Chen and Jain to create a equipment model as disclosed by Sonderman. The motivation to combine would have been that Yunemura teaches heat modeling on a silicon chip affecting the thermal conductivity (Yunemura: Pg.1407 Section 2) based on various thicknesses and Sonderman is solving the same issue for the equipment model that for example model the equipment for depositing the various layers and affects on heat and pressure. ANSYS is known in art to be used as thermal & pressure modeling tool based on finite element analysis. Yunemura's teaching thereby facilitates computer-encoded differential equations solving which is considered to be prime issue by Jain (Jain: See Section III, Networking and Dedicated MPE's for solving the computer-encoded differential equations).

Art Unit: 2128

System claim 49 discloses similar limitations as claim 22 and is rejected for the same reasons as claim 22.

5. Claims 24 & 51 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 6,802,045 issued to Sonderman et al (Sonderman hereafter), in view of U.S. Patent No. 5,719,796 issued to Vincent M.C. Chen (Chen hereafter), in view of IEEE article "Mathematic-physical engine: parallel processing for modeling and simulation of physical phenomena" by Jain et al (Jain hereafter), further in view of U.S. Patent No. 6,812,045 issued to Mehrdad Nikoonahad (Nikoonahad hereafter).

Regarding Claim 24

Teachings of *Sonderman, Chen and Jain* are disclosed in claim 1 rejection above.

Sonderman provides examples of the processing tool as etch and photolithography tools (Col.4 Lines 26-31) *but does not explicitly disclose chemical vapor and physical vapor deposition system*. Chen teaches fabrication equipment as Chemical Vapor Deposition (CVD) system (Col.5 Lines 1-5) but does not teach physical vapor deposition system. *Jain is moot on such teachings*.

Nikoonahad teaches deposition tools to include chemical vapor and physical vapor deposition system (Nikoonahad: Col.24 Lines 3-49).

It would have been obvious to one (e.g. a designer) of ordinary skill in the art at the time the invention was made to apply the teachings of Nikoonahad to Sonderman, Chen and Jain. The motivation to combine would have been that Nikoonahad and Sonderman-Chen are analogous art and both are modeling the

Application/Control Number: 10/673,467 Page 24

Art Unit: 2128

semiconductor processing and providing feedback to the semiconductor processing tool (Sonderman: Abstract; Nikoonahad: Col.3; Col.93 Lines 20-35; Chen:Summary).

Regarding Claim 51

System claim 51 discloses similar limitations as claim 24 and is rejected for the same reasons as claim 24.

Conclusion

- 1. All claims are rejected.
- The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
- 3. Examiner's Note: Examiner has cited particular columns and line numbers in the references applied to the claims above for the convenience of the applicant. Although the specified citations are representative of the teachings of the art and are applied to specific limitations within the individual claim, other passages and figures may apply as well. It is respectfully requested from the applicant in preparing responses, to fully consider the references in their entirety as potentially teaching all or part of the claimed invention, as well as the context of the passage as taught by the prior art or disclosed by the Examiner.

In the case of amending the claimed invention, Applicant is respectfully requested to indicate the portion(s) of the specification which dictate(s) the structure relied on for proper interpretation and also to verify and ascertain the metes and bounds of the claimed invention.

Communication

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Akash Saxena whose telephone number is (571) 272-8351. The examiner can normally be reached on 9:30 - 6:00 PM M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kamini S. Shah can be reached on (571)272-2279. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Akash Saxena/

KAMINI SHAH
KAMINI SHAH
EXAMINER